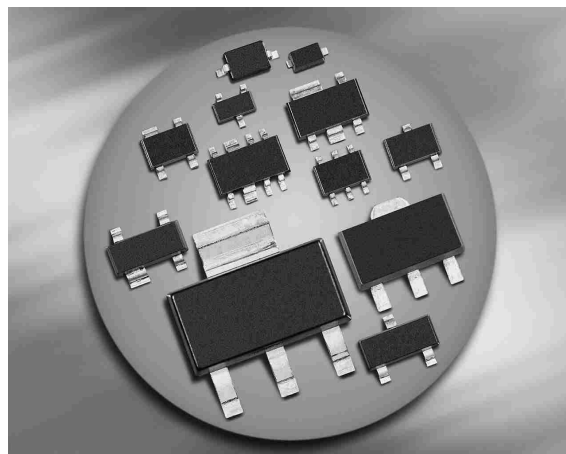
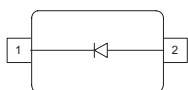


Silicon Schottky Diodes

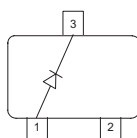
- For low-loss, fast-recovery, meter protection, bias isolation and clamping application
- Guard ring protected
- Low forward voltage
- Pb-free (RoHS compliant) package ¹⁾
- Qualified according AEC Q101



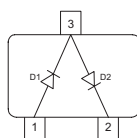
BAT54-02LRH
BAT54-02V
BAT54-03W



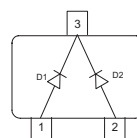
BAT54
BAT54W



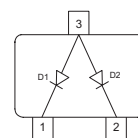
BAT54-04
BAT54-04W



BAT54-05
BAT54-05W



BAT54-06
BAT54-06W



Type	Package	Configuration	L_S (nH)	Marking
BAT54	SOT23	single	1.8	T
BAT54-02LRH	TSLP-2-7	single	0.4	54
BAT54-02V	SC79	single	0.6	b
BAT54-03W*	SOD323	single	1.8	5/blue
BAT54-04	SOT23	series	1.8	TS
BAT54-04W	SOT323	series	1.4	TS
BAT54-05	SOT23	common cathode	1.8	TC
BAT54-05W	SOT323	common cathode	1.4	TC
BAT54-06	SOT23	common anode	1.8	TA
BAT54-06W	SOT323	common anode	1.4	TA
BAT54W	SOT323	single	1.4	T5

* Preliminary data

¹Pb-containing package may be available upon special request

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	30	V
Forward current	I_F	200	mA
Non-repetitive peak surge forward current ($t \leq 10 \text{ ms}$)	I_{FSM}	600	
Repetitive peak forward current ¹⁾ $t_p \leq 1 \text{ s}, \delta = 0.5$	I_{FRM}	300	mA
Total power dissipation	P_{tot}		mW
BAT54, $T_S \leq 94^\circ\text{C}$		230	
BAT54-02LRH, $T_S \leq 135^\circ\text{C}$		230	
BAT54-02V, $T_S \leq 126^\circ\text{C}$		230	
BAT54-03W, $T_S \leq \text{tbd } ^\circ\text{C}$		230	
BAT54-04, $T_S \leq 71^\circ\text{C}$		230	
BAT54-04W, $T_S \leq 117^\circ\text{C}$		230	
BAT54-05, $T_S \leq 48^\circ\text{C}$		230	
BAT54-05W, $T_S \leq 110^\circ\text{C}$		230	
BAT54-06, $T_S \leq 71^\circ\text{C}$		230	
BAT54-06W, $T_S \leq 117^\circ\text{C}$		230	
BAT54W, $T_S \leq 125^\circ\text{C}$		230	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-65 ... 150	

¹⁾Device mounted on epoxy PCB 40 x 40 x 1.5 mm / 6 cm² Cu

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BAT54		≤ 245	
BAT54-02LRH		≤ 65	
BAT54-02V		≤ 105	
BAT54-03W		$\leq tbd$	
BAT54-04		≤ 345	
BAT54-04W		≤ 145	
BAT54-05		≤ 445	
BAT54-05W		≤ 175	
BAT54-06		≤ 345	
BAT54-06W		≤ 145	
BAT54W		≤ 110	

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage ²⁾ <i>I</i> _(BR) = 10 μA	<i>V</i> _(BR)	30	-	-	V
Reverse current ²⁾ <i>V</i> _R = 25 V	<i>I</i> _R	-	-	2	μA
Forward voltage ²⁾ <i>I</i> _F = 0.1 mA <i>I</i> _F = 1 mA <i>I</i> _F = 10 mA <i>I</i> _F = 30 mA <i>I</i> _F = 100 mA	<i>V</i> _F	- - - - -	- - - - -	240 320 400 500 800	mV

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

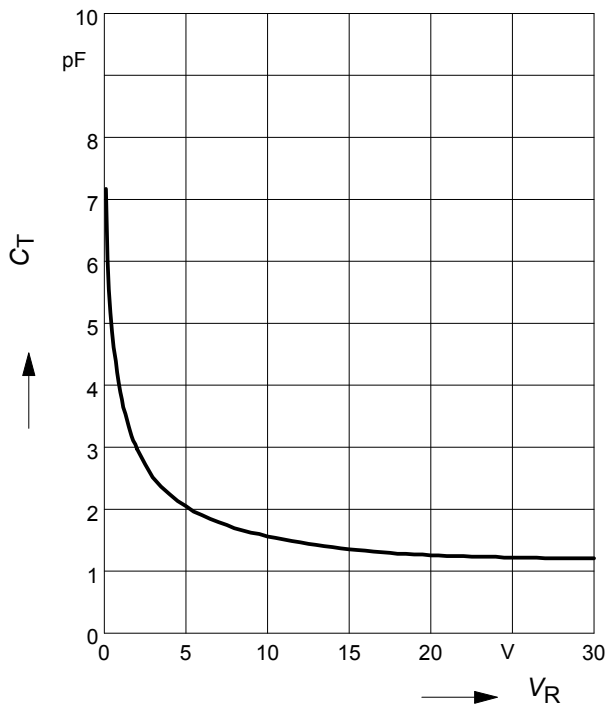
²⁾Pulsed test: $t_p = 300 \mu\text{s}$; $D = 0.01$

Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics					
Diode capacitance $V_R = 1\text{ V}$, $f = 1\text{ MHz}$	C_T	-	-	10	pF
Reverse recovery time $I_F = 10\text{ mA}$, $I_R = 10\text{ mA}$, measured $I_R = 1\text{ mA}$, $R_L = 100\text{ }\Omega$	t_{rr}	-	-	5	ns

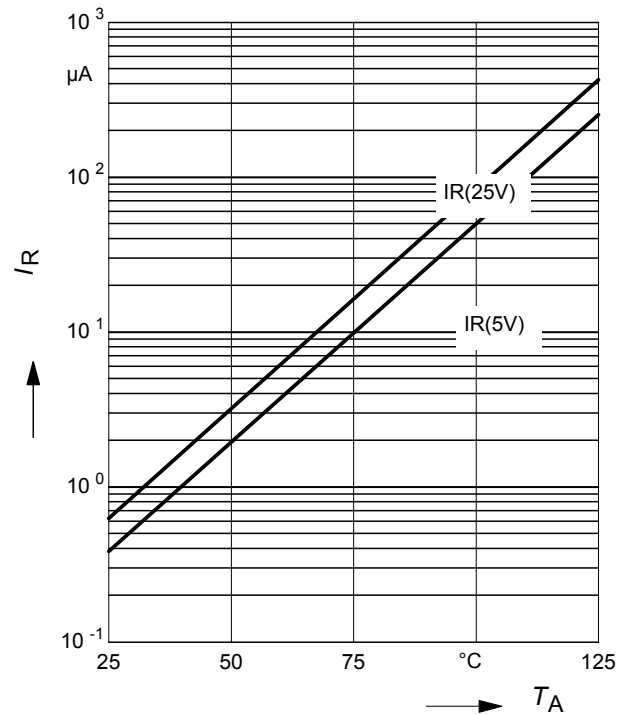
Diode capacitance $C_T = f(V_R)$

$f = 1\text{MHz}$



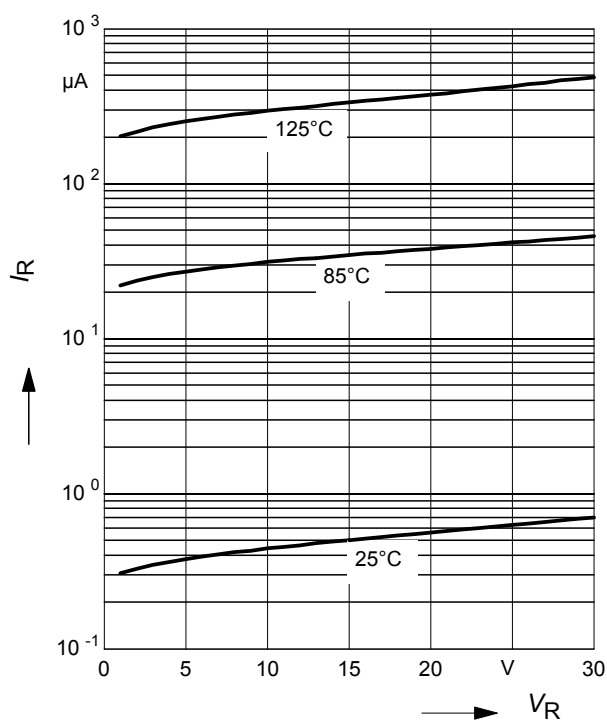
Reverse current $I_R = f(T_A)$

$V_R = \text{Parameter}$



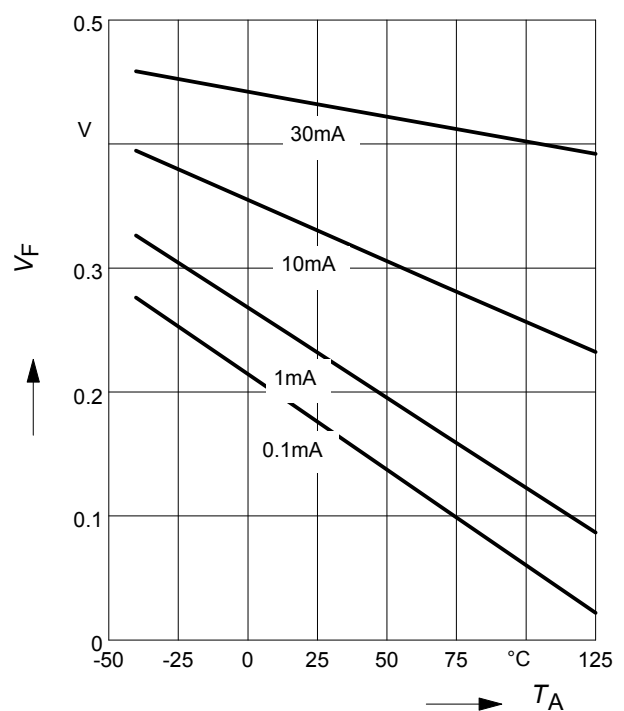
Reverse current $I_R = f(V_R)$

$T_A = \text{Parameter}$



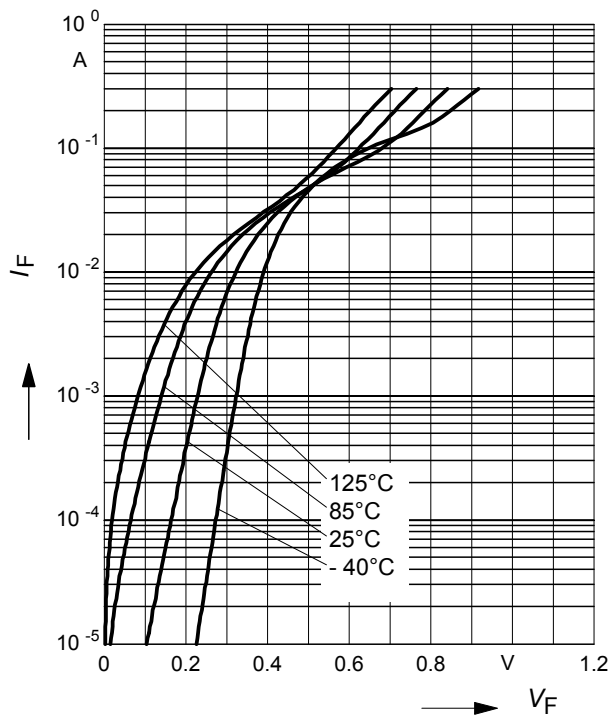
Forward Voltage $V_F = f(T_A)$

$I_F = \text{Parameter}$



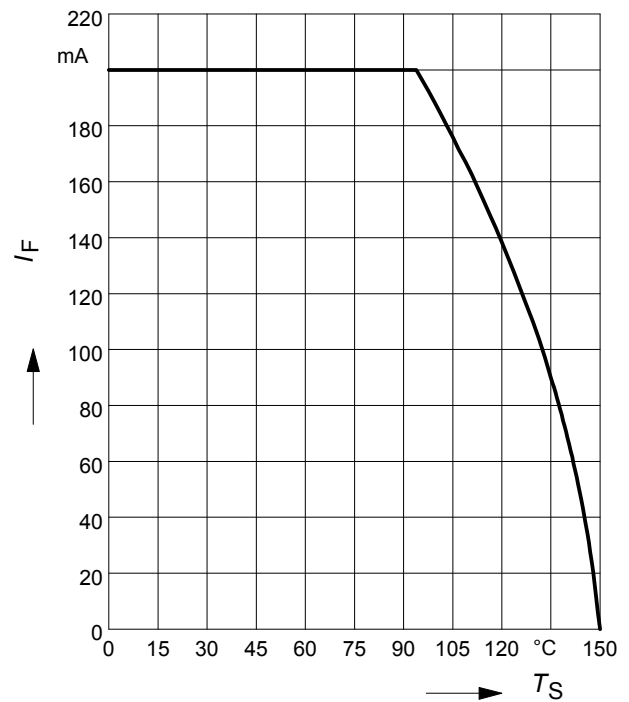
Forward current $I_F = f(V_F)$

T_A = Parameter



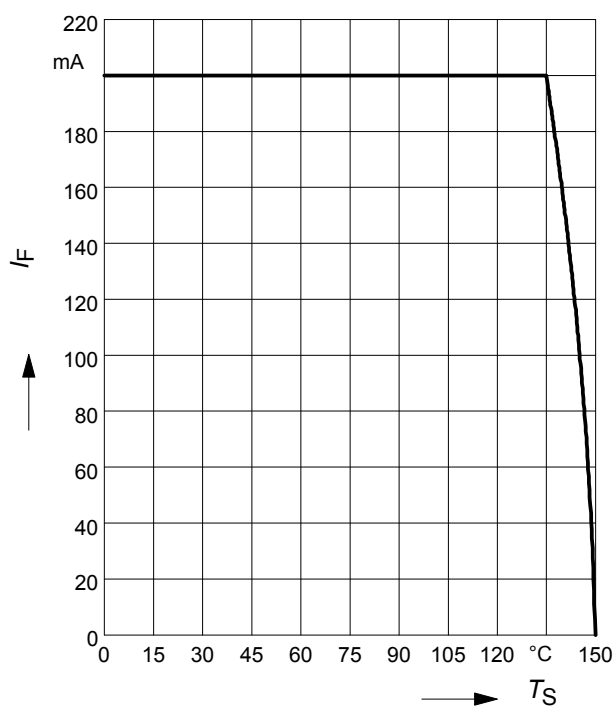
Forward current $I_F = f(T_S)$

BAT54



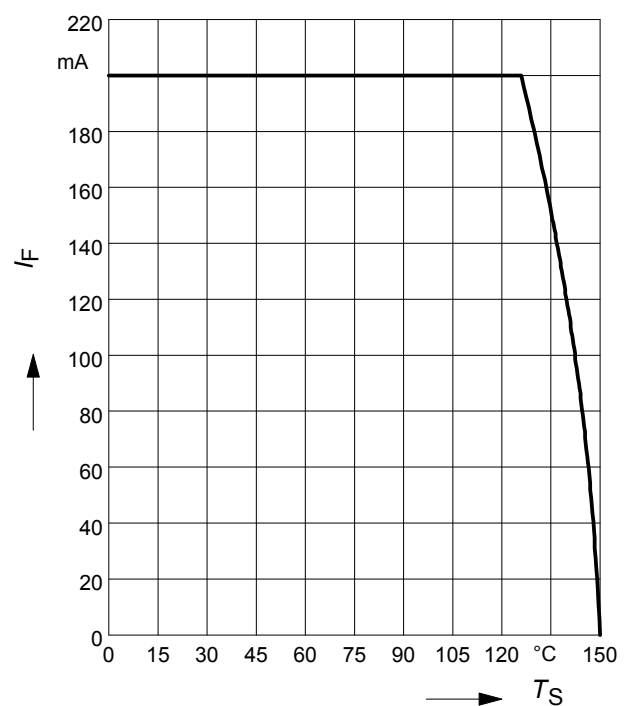
Forward current $I_F = f(T_S)$

BAT54-02LRH



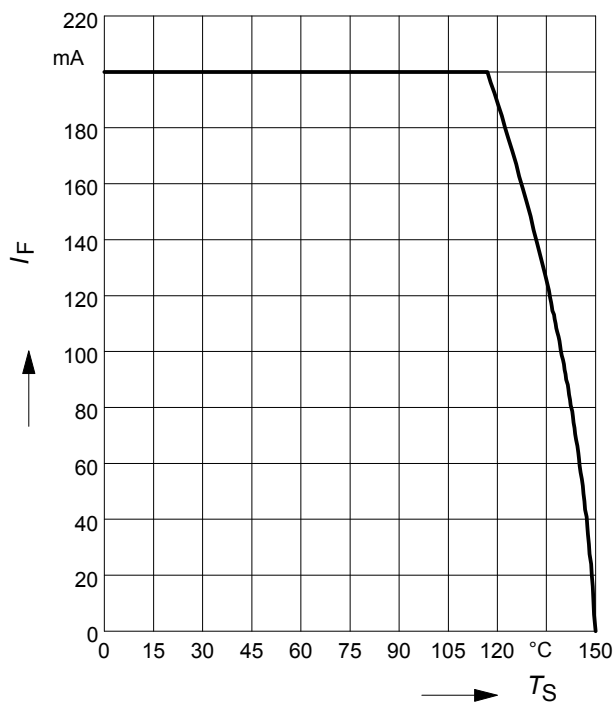
Forward current $I_F = f(T_S)$

BAT54-02V



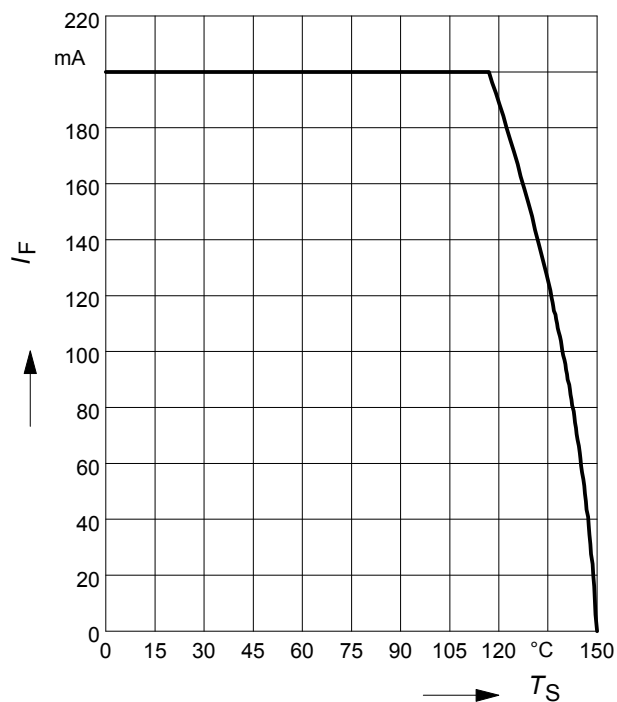
Forward current $I_F = f(T_S)$

BAT54-04



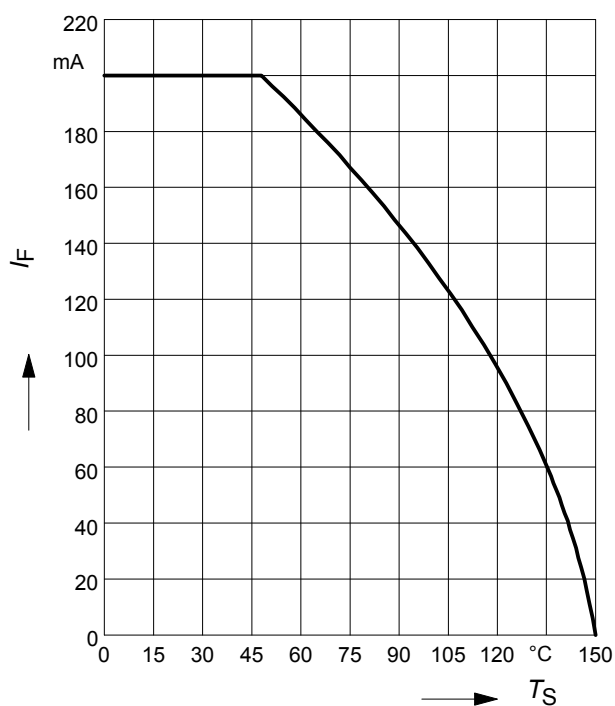
Forward current $I_F = f(T_S)$

BAT54-04W



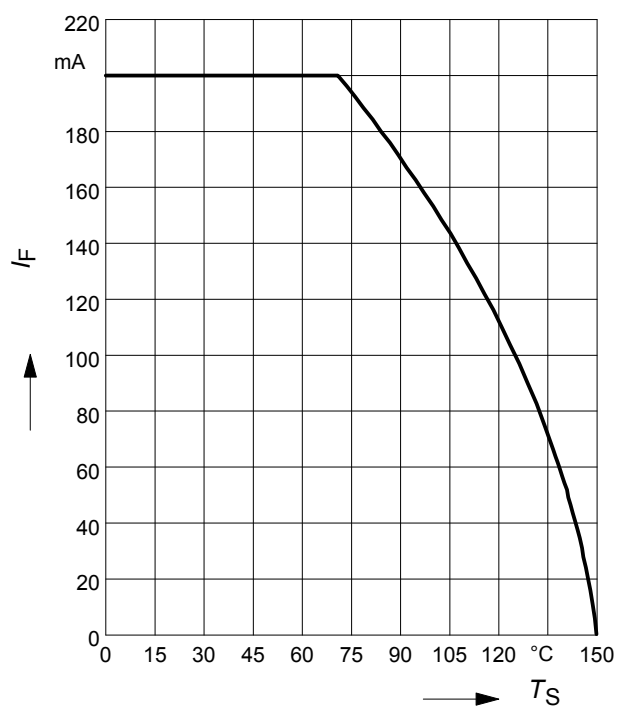
Forward current $I_F = f(T_S)$

BAT54-05



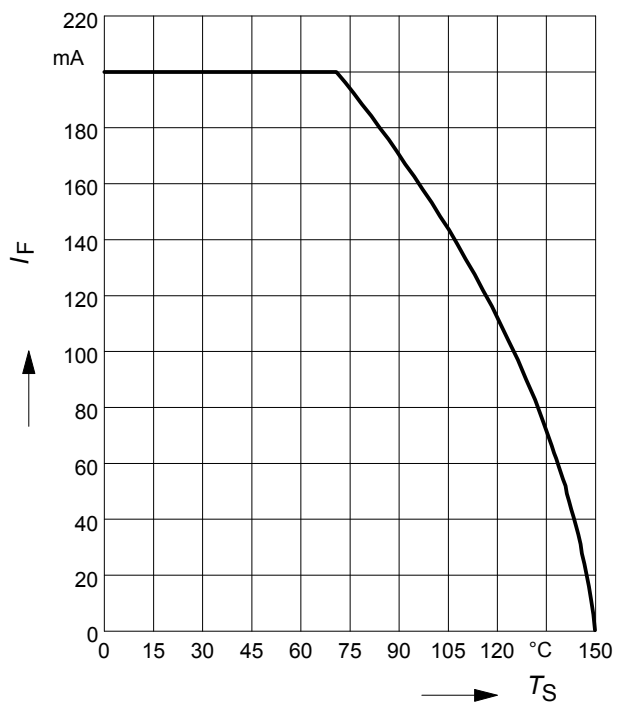
Forward current $I_F = f(T_S)$

BAT54-05W



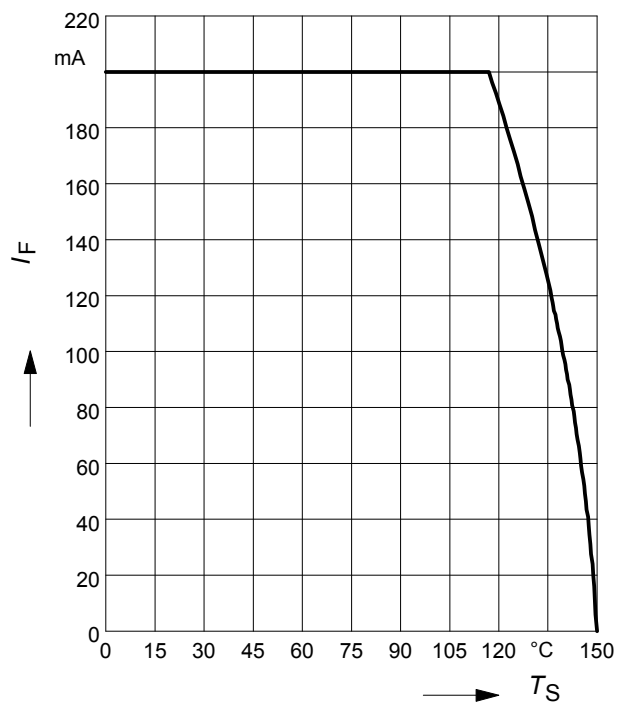
Forward current $I_F = f(T_S)$

BAT54-06



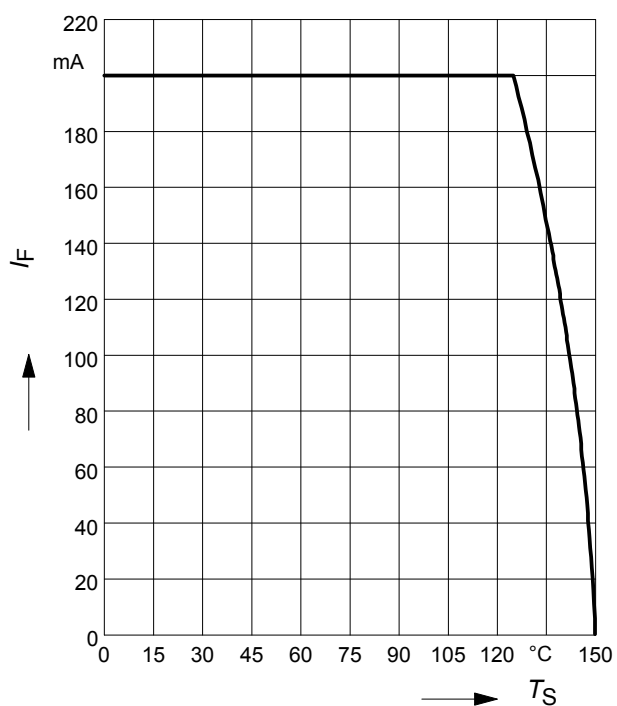
Forward current $I_F = f(T_S)$

BAT54-06W

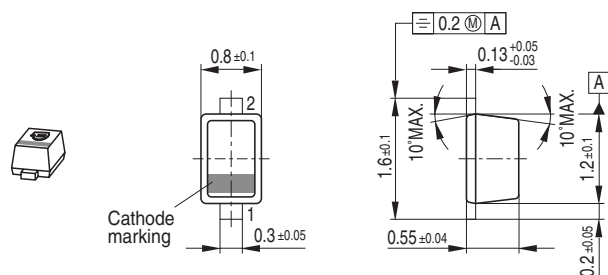


Forward current $I_F = f(T_S)$

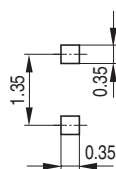
BAT54W



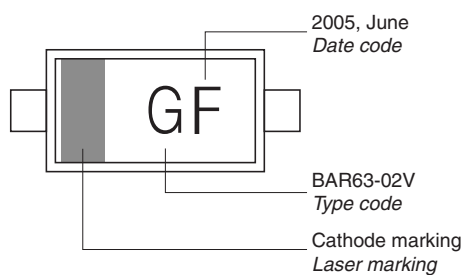
Package Outline



Foot Print

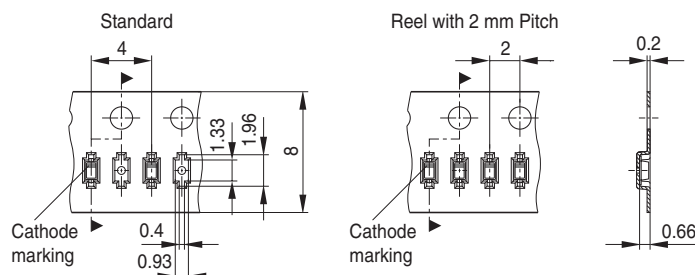


Marking Layout (Example)



Standard Packing

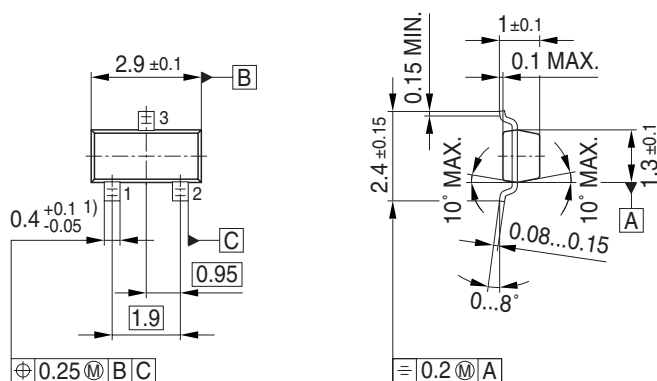
Reel ø180 mm = 3.000 Pieces/Reel
 Reel ø180 mm = 8.000 Pieces/Reel (2 mm Pitch)
 Reel ø330 mm = 10.000 Pieces/Reel



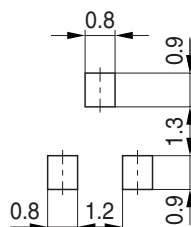
Date Code marking for discrete packages with one digit (SCD80, SC79, SC75¹⁾) CES-Code

Month	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014
01	a	p	A	P	a	p	A	P	a	p	A	P
02	b	q	B	Q	b	q	B	Q	b	q	B	Q
03	c	r	C	R	c	r	C	R	c	r	C	R
04	d	s	D	S	d	s	D	S	d	s	D	S
05	e	t	E	T	e	t	E	T	e	t	E	T
06	f	u	F	U	f	u	F	U	f	u	F	U
07	g	v	G	V	g	v	G	V	g	v	G	V
08	h	x	H	X	h	x	H	X	h	x	H	X
09	j	y	J	Y	j	y	J	Y	j	y	J	Y
10	k	z	K	Z	k	z	K	Z	k	z	K	Z
11	l	2	L	4	l	2	L	4	l	2	L	4
12	n	3	N	5	n	3	N	5	n	3	N	5

1) New Marking Layout for SC75, implemented at October 2005.

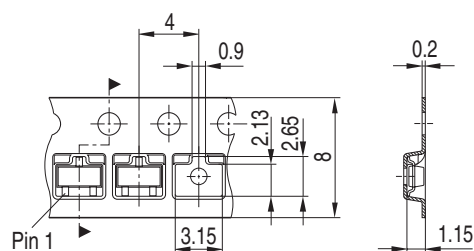


Foot Print

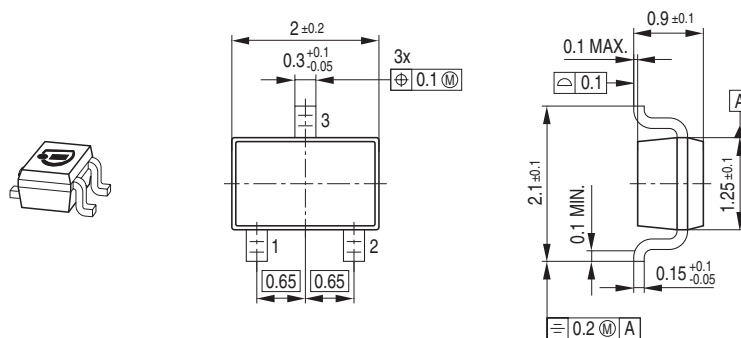


The diagram shows a top-down view of a BCW66 LED package. It is a rectangular component with four pins. The top pin is labeled 'Pin 1'. The package has a central rectangular area containing the text 'EHS' and '65'. To the right of this area, the text '2005, June' and 'Date code (YM)' is shown. Above the package, the Infineon logo and the text 'Manufacturer' are displayed. Below the package, the text 'BCW66' and 'Type code' are shown.

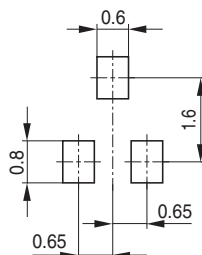
Reel ø180 mm = 3.000 Pieces/Reel
Reel ø330 mm = 10.000 Pieces/Reel



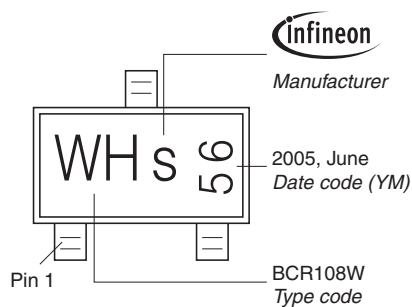
Package Outline



Foot Print

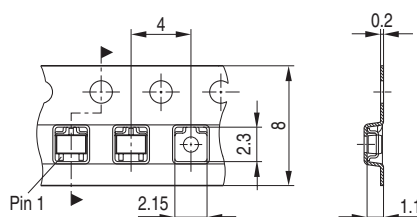


Marking Layout (Example)

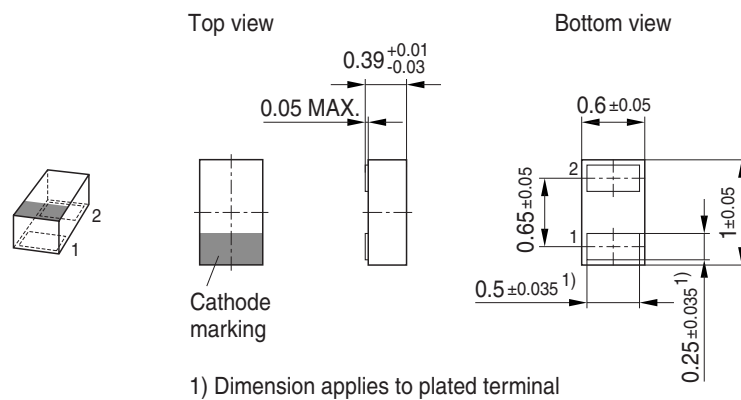


Standard Packing

Reel $\varnothing 180$ mm = 3.000 Pieces/Reel
 Reel $\varnothing 330$ mm = 10.000 Pieces/Reel

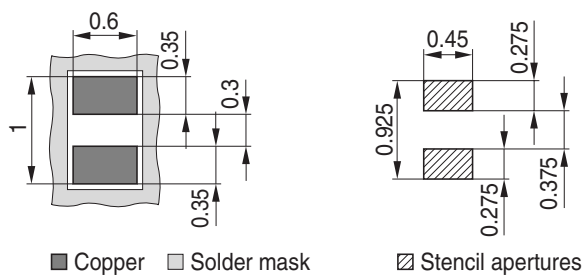


Package Outline

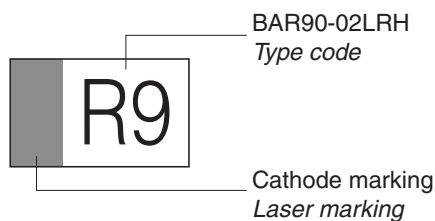


Foot Print

For board assembly information please refer to Infineon website "Packages"



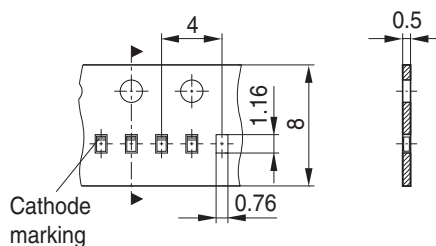
Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel

Reel ø330 mm = 50.000 Pieces/Reel (optional)



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